CLAIMS:

1. A dielectric ceramic composite characterised by comprising (BaNdSm)TiO<sub>3</sub>, ZnO, SiO<sub>2</sub>, CuO, Al<sub>2</sub>O<sub>3</sub>, MgO, B<sub>2</sub>O<sub>3</sub>, Bi<sub>2</sub>O<sub>3</sub> and either BaCO<sub>3</sub> or BaO.

9

- 2. A dielectric ceramic composite as claimed in claim 1, characterized in that the total weight of the said ZnO, SiO<sub>2</sub>, CuO, Al<sub>2</sub>O<sub>3</sub>, MgO, B<sub>2</sub>O<sub>3</sub>, Bi<sub>2</sub>O<sub>3</sub> and either BaCO<sub>3</sub> or BaO is about 20% through 30% of the weight of the said (BaNdSm)TiO<sub>3</sub>.
- 3. A dielectric ceramic composite as claimed in claim 2, characterized in that a ratio of the total weight of the said ZnO, SiO<sub>2</sub>, CuO, Al<sub>2</sub>O<sub>3</sub>, MgO, B<sub>2</sub>O<sub>3</sub> and either BaCO<sub>3</sub> or BaO with the weight of the said Bi<sub>2</sub>O<sub>3</sub> is in a range of 0.67 to 1.50.
  - 4. A dielectric ceramic composite as claimed in claim 2 or 3, characterized in that the average of the grain sizes of the said SiO<sub>2</sub>, CuO and Al<sub>2</sub>O<sub>3</sub> is no more than 30 nm.
- 15 5. An electronic device comprising the dielectric ceramic composite according to one of the claims 1-4